

Erratum to: Nonlinear optical properties of asymmetric n-type double δ -doped GaAs quantum well under intense laser field^{*}

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The form of the parameters α and z_o defined in equation (2) are mistyped in the original article. The correct version of these parameters is given below:

$$\alpha = \frac{e^2(2m^*)^{3/2}}{15\pi\epsilon\hbar^3}, \quad z_{oL} = \left(\frac{2\epsilon\alpha^3}{\pi e^2 N_{2d}^L}\right)^{1/5}, \quad z_{oR} = \left(\frac{2\epsilon\alpha^3}{\pi e^2 N_{2d}^R}\right)^{1/5}$$

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